



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT ZENER
SILICON PLANAR POWER ZENER DIODES
VOLTAGE RANGE 5.1V

MMPZ5231BAGP-A

FEATURE

- * High temperature soldering type.
- * ESD rating of class 3(>16 kV) per human body model.
- * Silicon planar zener diodes.
- * Silicon-oxide passivated junction.
- * Low temperature coefficient voltage
- * 200 mW Rating on FR-4 or FR-5 Board

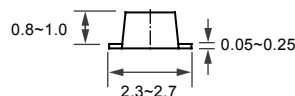
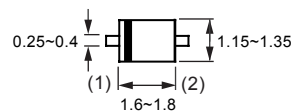
MECHANICAL

- * Void-free, Transfer-molded, Thermosetting plastic case
- * SOD-323S Packaging.
- * Cathode indicated by polarity band.
- * Mounting position: Any.



SOD-323S

CIRCUIT



Dimensions in millimeters

SOD-323S

MAXIMUM RATINGS (At $T_A = 25^{\circ}\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Zener Current (see Table "Characteristics")	-	-	-
Max. Steady State Power Dissipation @ $T_A=25^{\circ}\text{C}$	P_D	200	mW
Max. Operating Temperature Range	T_J	-65 to +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS (At $T_A = 25^{\circ}\text{C}$ unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	-	-	625	$^{\circ}\text{C/W}$
Max. Instantaneous Forward Voltage at $I_F = 10\text{mA}$	V_F	-	-	1.0	Volts

- NOTES :
1. The JEDEC type numbers listed have a standard tolerance on the normal zener voltage of $\pm 10\%$. Suffix B= $\pm 5\%$.
 2. The zener impedance is derived from 1KHz AC voltage, which results when an AC current having an RMS value equal to 10% of DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve to eliminate unstable units.
 3. Valid provided that electrodes at distance of 10mm from case are kept ambient temperature.
 4. Measured under thermal equilibrium and DC test conditions.
 5. The rating listed in the electrical characteristics table is maximum peak, non-repetitive, reverse surge current of 1/2 square wave or equivalent sine wave pulse of 1/120 second duration superimposed on the test current, I_{ZT} , per JEDEC registration.

2011-08

ELECTRICAL CHARACTERISTICS (MMPZ5231BAGP-A)

TYPE	Zener voltage V _Z (V) @ I _{ZT}			Test current I _{ZT} (mA)	Maximum Zener impedance			Maximum reverse leakage current	
	Min	Nom	Max		Z _{ZT} at I _{ZT} (Ω)	Z _{ZK} (Ω)	at I _{ZK} (mA)	I _R (μA)	at V _R (V)
	Volts	Volts	Volts						
MMPZ5231BAGP-A	4.85	5.1	5.36	5	60	451	1	1.8	2

RATING CHARACTERISTIC CURVES (MMPZ5231BAGP-A)

Fig.1 POWER DISSIPATION VS. AMBIENT TEMP.

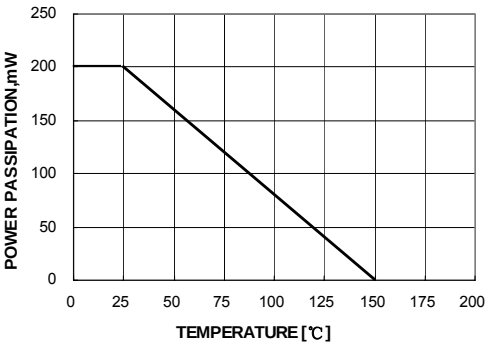


Fig.2 TYPICAL CAPACITANCE

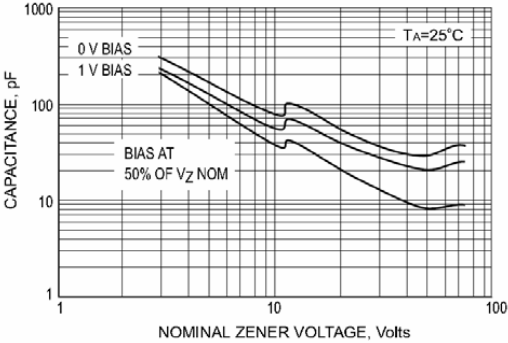


Fig.3 ZENER BREAKDOWN CHARACTERISTICS

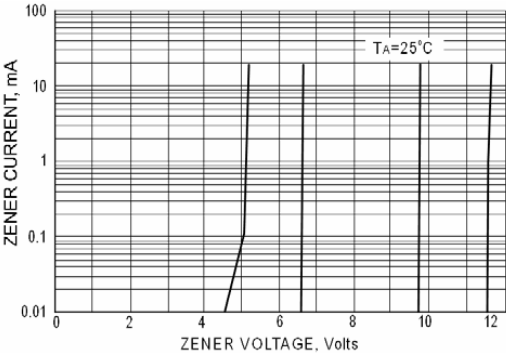
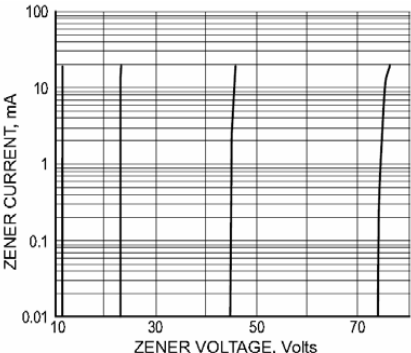


Fig.4 ZENER BREAKDOWN CHARACTERISTICS





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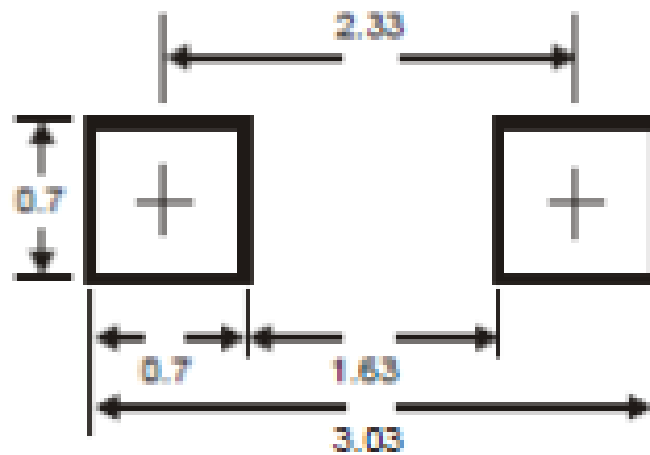
SURFACE MOUNT

RECOMMENDED FOOT PRINT

all dimensions in mm

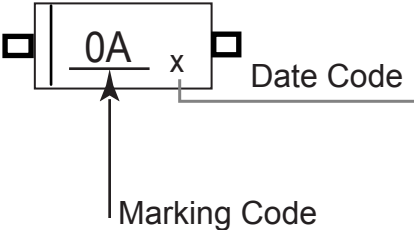
SOD-323S

SOD-323S



The Marking and Part No. for MMPZ5231BAGP-A (SOD-323S)

Marking:



Date Code Standard

Date Code	A	B	C	D	E	F	G	H	J	K	L	M
2013Year	JAN.	FEB.	MAR.	APR	MAY	JUNE	JULY	AUG.	SEP.	OCT	NOV.	DEC.

Date Code	N	P	Q	R	S	T	U	V	W	X	Y	Z
2014Year	JAN.	FEB.	MAR.	APR	MAY	JUNE	JULY	AUG.	SEP.	OCT	NOV.	DEC.

CUSTOMER :	APPROVED : DANY	 CHENMKO LTD.
APPROVED :	CHECKED : ANGEL	
CHECKED :	DRAWN : BEN	
		DRAWING No. :